



**PATENT**  
**29925/37672**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: Young-Hun Bae and  
Won-Sung Park

Serial No.: 09/940,774

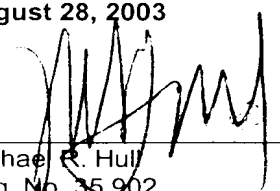
Filed: August 27, 2001

For: Method for Forming a Gate  
of a High Integration  
Semiconductor Device

Group Art Unit: 2823

Examiner: William M. Brewster

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)  
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**AMENDMENT**

Commissioner for Patents  
P.O. Box 1450 Alexandria  
Virginia 22313-1450

Dear Sir:

Please enter the following amendment in the above-referenced patent application.